NSN 5961-00-902-3444

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Inclosure Material:

Metal

Overall Length:

1.803 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Thread Size:

0.312 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

55.0 base to emitter voltage, dc and 40.0 collector to emitter voltage, dc and 15.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 7.50 amperes source cutoff current and 20.00 amperes source cutoff current

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0